

KSC1393

TV VHF Tuner RF Amplifier (Forward AGC)

- High Current Gain Bandwidth Product : f_T=700MHz (TYP.)
- Low Noise Figure: NF=3.0dB (MAX.) at f=200MHz
- Low Reverse Transfer Capacitance : C_{RE}=0.5pF (MAX.)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	4	V
I _C	Collector Current	20	mA
P _C	Collector Power Dissipation	250	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C}=10\mu A, I_{E}=0$	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5$ mA, $I_B=0$	30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μA, I _C =0	4			V
I _{CBO}	Collector Cut-off Current	V_{CB} =20V, I_E =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =2mA	40		180	,
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =3mA	400	700		MHz
C _{RE}	Reverse Transfer Capacitance	V _{CB} =10V, I _E =0, f=1MHz		0.35	0.5	pF
G _{PE}	Power Gain	V _{CE} =10V, I _C =3mA f=200MHz	20	24		dB
I _{AGC}	AGC Current	I _E at G _R = -30dB, f=200MHz		-10	-12	mA
NF	Noise Figure	V_{CE} =10V, I_{C} = 3mA f=200MHz		2.0	3.0	dB

h_{FE} Classification

Classification	R	0	Y
h _{FE}	40 ~ 80	60 ~ 140	90 ~ 180

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Typical Characteristics

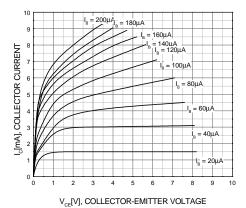


Figure 1. Static Characteristic

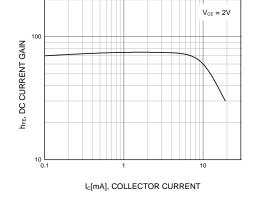


Figure 2. DC current Gain

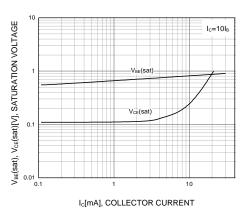


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

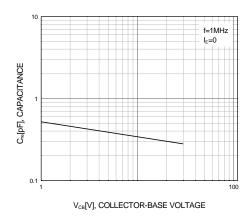


Figure 4. Reverse Capacitance

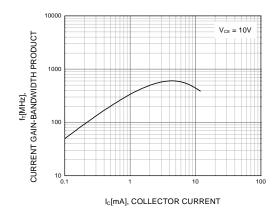


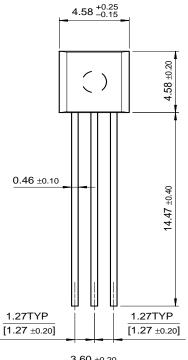
Figure 5. Current Gain Bandwidth Product

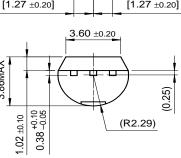
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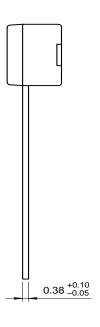


Package Dimensions

TO-92







Dimensions in Millimeters

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